



**THE DATASHEET OF  
MMFT960T1G**



# MMFT960T1

Preferred Device

## Power MOSFET 300 mA, 60 Volts

### N-Channel SOT-223

This Power MOSFET is designed for high speed, low loss power switching applications such as switching regulators, dc-dc converters, solenoid and relay drivers. The device is housed in the SOT-223 package which is designed for medium power surface mount applications.

#### Features

- Silicon Gate for Fast Switching Speeds
- Low Drive Requirement
- The SOT-223 Package can be Soldered Using Wave or Reflow
- The Formed Leads Absorb Thermal Stress During Soldering Eliminating the Possibility of Damage to the Die
- Pb-Free Package is Available

#### MAXIMUM RATINGS ( $T_C = 25^\circ\text{C}$ unless otherwise noted)

Rating	Symbol	Value	Unit
Drain-to-Source Voltage	$V_{DS}$	60	V
Gate-to-Source Voltage – Non-Repetitive	$V_{GS}$	$\pm 30$	V
Drain Current	$I_D$	300	mA <sub>dc</sub>
Total Power Dissipation @ $T_A = 25^\circ\text{C}$ (Note 1) Derate above $25^\circ\text{C}$	$P_D$	0.8 6.4	W mW/ $^\circ\text{C}$
Operating and Storage Temperature Range	$T_J, T_{stg}$	-65 to 150	$^\circ\text{C}$

#### THERMAL CHARACTERISTICS

Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	156	$^\circ\text{C}/\text{W}$
Maximum Temperature for Soldering Purposes Time in Solder Bath	$T_L$	260 10	$^\circ\text{C}$ S

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

1. Device mounted on a FR-4 glass epoxy printed circuit board using minimum recommended footprint.

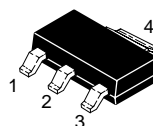
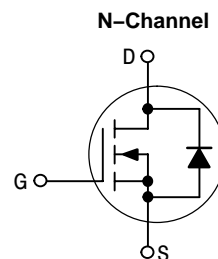


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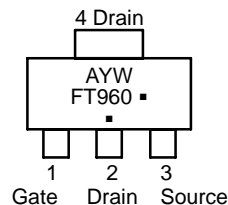
300 mA, 60 VOLTS

$R_{DS(on)} = 1.7 \Omega$



TO-261AA  
CASE 318E  
STYLE 3

#### MARKING DIAGRAM AND PIN ASSIGNMENT



A = Assembly Location  
Y = Year  
W = Work Week  
▪ = Pb-Free Package  
FT960 = Device Code  
(Note: Microdot may be in either location)

#### ORDERING INFORMATION

Device	Package	Shipping†
MMFT960T1	SOT-223	1000 Tape & Reel
MMFT960T1G	SOT-223 (Pb-Free)	1000 Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

Preferred devices are recommended choices for future use and best overall value.

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## ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
<b>OFF CHARACTERISTICS</b>					
Drain-to-Source Breakdown Voltage ( $V_{GS} = 0, I_D = 10 \mu\text{A}$ )	$V_{(BR)DSS}$	60	-	-	Vdc
Zero Gate Voltage Drain Current ( $V_{DS} = 60 \text{ V}, V_{GS} = 0$ )	$I_{DSS}$	-	-	10	$\mu\text{A}_{dc}$
Gate-Body Leakage Current ( $V_{GS} = 15 \text{ Vdc}, V_{DS} = 0$ )	$I_{GSS}$	-	-	50	$\text{nA}_{dc}$

## ON CHARACTERISTICS (Note 2)

Gate Threshold Voltage ( $V_{DS} = V_{GS}, I_D = 1.0 \text{ mA}_{dc}$ )	$V_{GS(th)}$	1.0	-	3.5	Vdc
Static Drain-to-Source On-Resistance ( $V_{GS} = 10 \text{ Vdc}, I_D = 1.0 \text{ A}$ )	$R_{DS(on)}$	-	-	1.7	$\Omega$
Drain-to-Source On-Voltage ( $V_{GS} = 10 \text{ V}, I_D = 0.5 \text{ A}$ ) ( $V_{GS} = 10 \text{ V}, I_D = 1.0 \text{ A}$ )	$V_{DS(on)}$	-	-	0.8 1.7	Vdc
Forward Transconductance ( $V_{DS} = 25 \text{ V}, I_D = 0.5 \text{ A}$ )	$g_{fs}$	-	600	-	$\text{mmhos}$

## DYNAMIC CHARACTERISTICS

Input Capacitance	$(V_{DS} = 25 \text{ V}, V_{GS} = 0, f = 1.0 \text{ MHz})$	$C_{iss}$	-	65	-	$\text{pF}$
Output Capacitance		$C_{oss}$	-	33	-	
Transfer Capacitance		$C_{rss}$	-	7.0	-	
Total Gate Charge	$(V_{GS} = 10 \text{ V}, I_D = 1.0 \text{ A}, V_{DS} = 48 \text{ V})$	$Q_g$	-	3.2	-	$\text{nC}$
Gate-Source Charge		$Q_{gs}$	-	1.2	-	
Gate-Drain Charge		$Q_{gd}$	-	2.0	-	

2. Pulse Test: Pulse Width  $\leq 300 \mu\text{s}$ , Duty Cycle  $\leq 2.0\%$ .

## TYPICAL ELECTRICAL CHARACTERISTICS

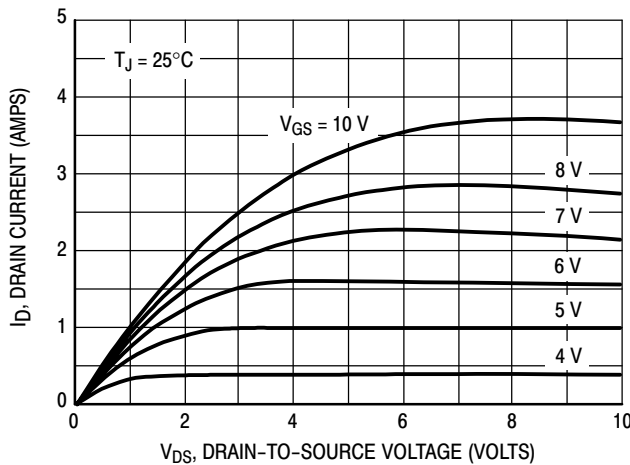


Figure 1. On-Region Characteristics

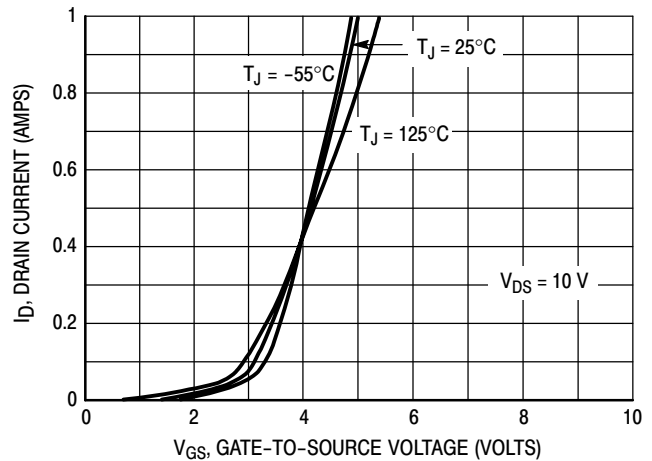


Figure 2. Transfer Characteristics

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## TYPICAL ELECTRICAL CHARACTERISTICS

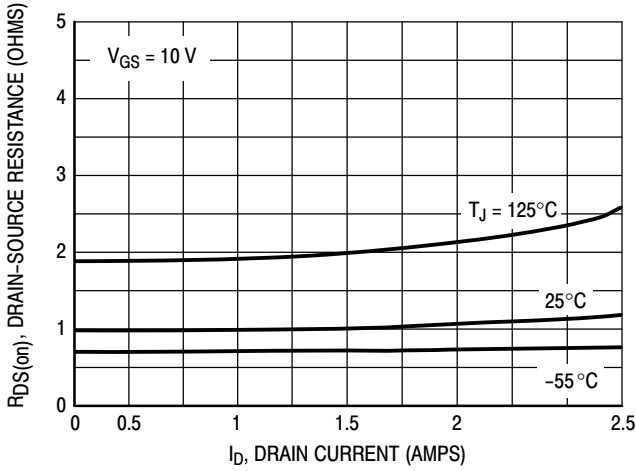


Figure 3. On-Resistance versus Drain Current

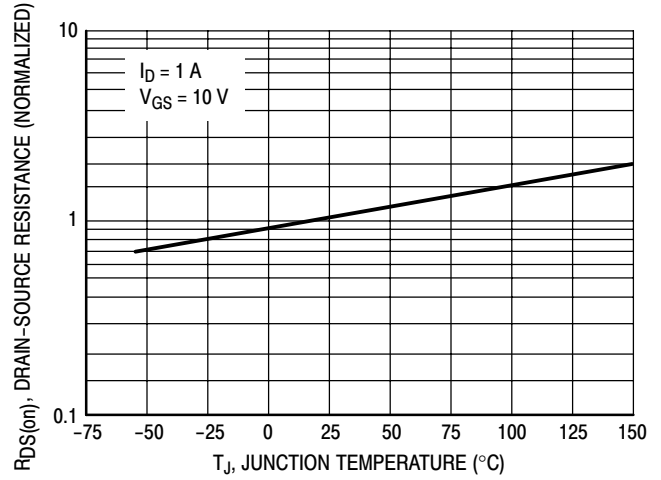


Figure 4. On-Resistance Variation with Temperature

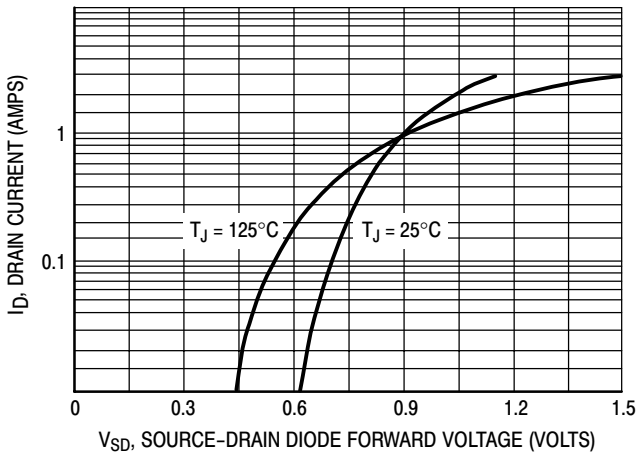


Figure 5. Source-Drain Diode Forward Voltage

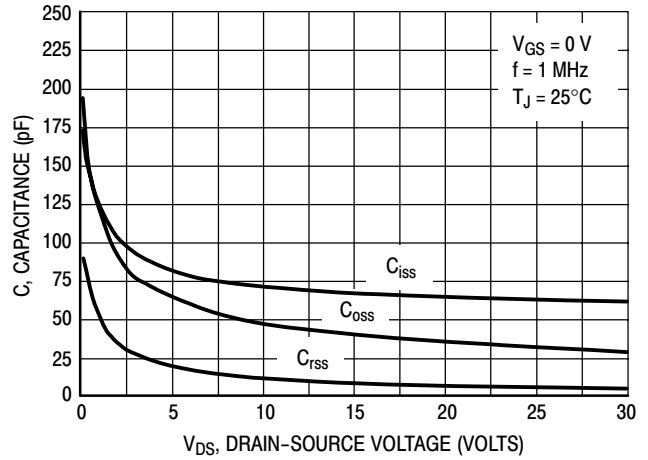


Figure 6. Capacitance Variation

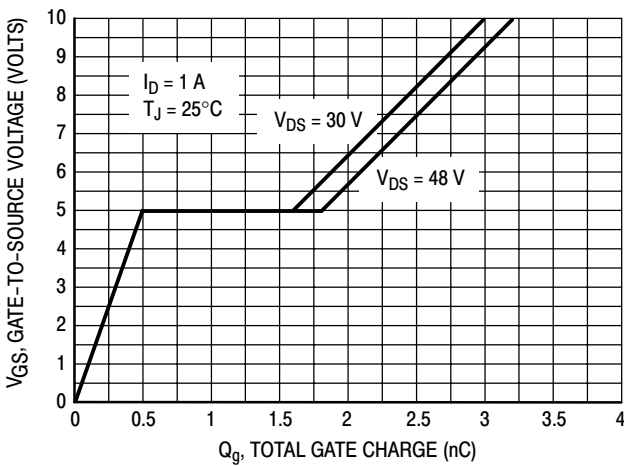


Figure 7. Gate Charge versus Gate-to-Source Voltage

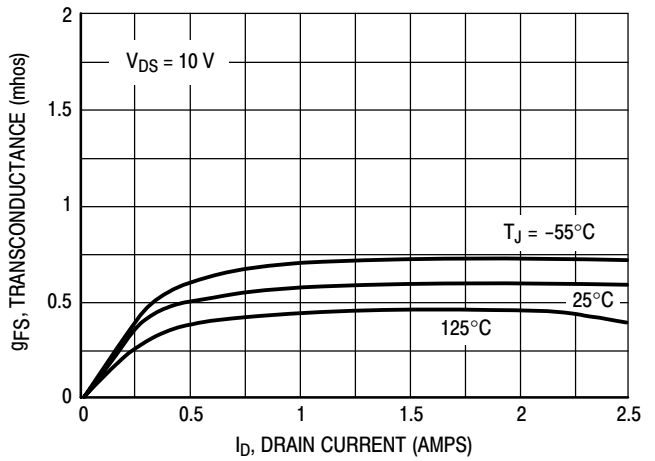
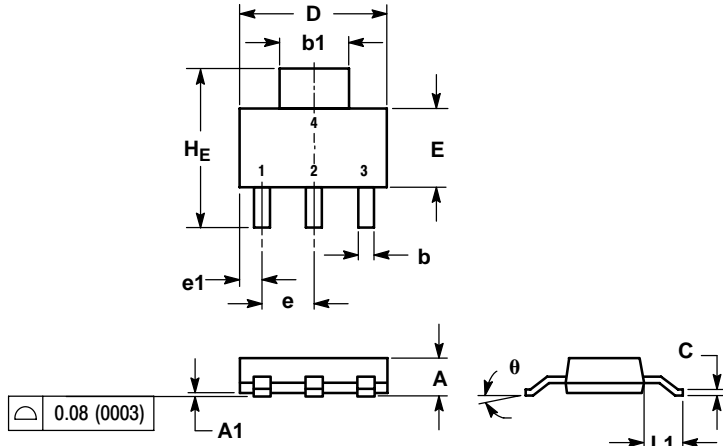


Figure 8. Transconductance

# MMFT960T1

## PACKAGE DIMENSIONS

SOT-223 (TO-261)  
CASE 318E-04  
ISSUE L

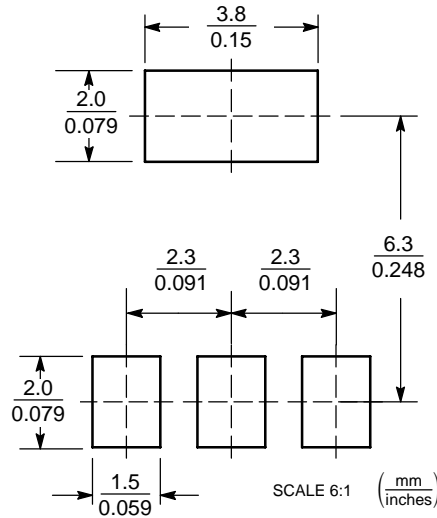


- NOTES:  
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.  
2. CONTROLLING DIMENSION: INCH.

DIM	MILLIMETERS			INCHES		
	MIN	NOM	MAX	MIN	NOM	MAX
A	1.50	1.63	1.75	0.060	0.064	0.068
A1	0.02	0.06	0.10	0.001	0.002	0.004
b	0.60	0.75	0.89	0.024	0.030	0.035
b1	2.90	3.06	3.20	0.115	0.121	0.126
c	0.24	0.29	0.35	0.009	0.012	0.014
D	6.30	6.50	6.70	0.249	0.256	0.263
E	3.30	3.50	3.70	0.130	0.138	0.145
e	2.20	2.30	2.40	0.087	0.091	0.094
e1	0.85	0.94	1.05	0.033	0.037	0.041
L1	1.50	1.75	2.00	0.060	0.069	0.078
HE	6.70	7.00	7.30	0.264	0.276	0.287
θ	0°	-	10°	0°	-	10°

- STYLE 3:  
PIN 1. GATE  
2. DRAIN  
3. SOURCE  
4. DRAIN

### SOLDERING FOOTPRINT\*



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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